July 1999 Revised November 2000

74LVT2244 • 74LVTH2244 Low Voltage Octal Buffer/Line Driver with 3-STATE Outputs and 25 Ω Series Resistors in the Outputs

General Description

FAIRCHILD

SEMICONDUCTOR

The LVT2244 and LVTH2244 are octal buffers and line drivers designed to be employed as memory address drivers, clock drivers and bus oriented transmitters or receivers which provides improved PC board density. The equivalent 25Ω -Series resistors helps reduce output overshoot and undershoot.

The LVTH2244 data inputs include bushold, eliminating the need for external pull-up resistors to hold unused inputs.

These octal buffers and line drivers are designed for lowvoltage (3.3V) V_{CC} applications, but with the capability to provide a TTL interface to a 5V environment. The LVT2244 and LVTH2244 are fabricated with an advanced BiCMOS technology to achieve high speed operation similar to 5V ABT while maintaining low power dissipation.

Features

- Input and output interface capability to systems at 5V V_{CC}
- Equivalent 25Ω-Series resistors on outputs
- Bushold data inputs eliminate the need for external pull-up resistors to hold unused inputs (74LVTH2244), also available without bushold feature (74LVT2244).
- Live insertion/extraction permitted
- Power Up/Down high impedance provides glitch-free bus loading
- Outputs source/sink –12 mA/+12 mA
- Latch-up performance exceeds 500 mA
- ESD performance: Human-body model > 2000V Machine model > 200V

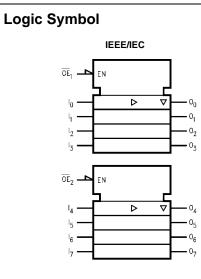
Charged-device model > 1000V

Ordering Code:

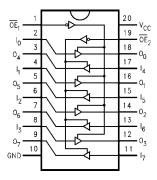
Order Number	Package Number	Package Description
74LVT2244WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74LVT2244SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LVT2244MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74LVTH2244WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74LVTH2244SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LVTH2244MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

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Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_1, \overline{OE}_2$	3-STATE Output Enable Inputs
I ₀ —I ₇	Inputs
O ₀ -O ₇	Outputs

Truth Tables

Inp	uts	Outputs			
OE ₁	I _n	(Pins 12, 14, 16, 18)			
L	L	L			
L	н	Н			
н	х	Z			
Inp	uts	Outputs			
Inp OE ₂	uts I _n	Outputs (Pins 3, 5, 7, 9)			
· ·	-				
· ·	-				

H = HIGH Voltage Level L = LOW Voltage Level X = Immaterial Z = High Impedance

Symbol	Parameter	Value	Conditions	Units
V _{CC}	Supply Voltage	-0.5 to +4.6		V
VI	DC Input Voltage	-0.5 to +7.0		V
Vo	DC Output Voltage	-0.5 to +7.0	Output in 3-STATE	V
		-0.5 to +7.0	Output in HIGH or LOW State (Note 2)	V
I _{IK}	DC Input Diode Current	-50	V _I < GND	mA
I _{ОК}	DC Output Diode Current	-50	V _O < GND	mA
I _O	DC Output Current	64	V _O > V _{CC} Output at HIGH State	mA
		128	V _O > V _{CC} Output at LOW State	mA
Icc	DC Supply Current per Supply Pin	±64		mA
I _{GND}	DC Ground Current per Ground Pin	±128		mA
T _{STG}	Storage Temperature	-65 to +150		°C

Recommended Operating Conditions

Symbol	Parameter	Min	Max	Units
V _{CC}	Supply Voltage	2.7	3.6	V
VI	Input Voltage	0	5.5	V
I _{ОН}	HIGH-Level Output Current		-12	س ۸
I _{OL}	LOW-Level Output Current		12	mA
T _A	Free-Air Operating Temperature	-40	85	°C
$\Delta t / \Delta V$	Input Edge Rate, V _{IN} = 0.8V–2.0V, V _{CC} = 3.0V	0	10	ns/V

Note 1: Absolute Maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute maximum rated conditions is not implied. or conditions Note 2: I_{O} Absolute Maximum Rating must be observed.

DC Electrical Characteristics

			V _{cc}	T _A =	40°C to +8	5°C			
Symbol	Parameter	Parameter		Min	Typ (Note 3)	Max	Units	Conditions	
V _{IK}	Input Clamp Diode Voltage		2.7			-1.2	V	I _I = -18 mA	
VIH	Input HIGH Voltage		2.7–3.6	2.0			V	$V_0 \le 0.1V$ or	
V _{IL}	Input LOW Voltage		2.7–3.6			0.8	v	$V_O \geq V_{CC} - 0.1V$	
V _{OH}	Output HIGH Voltage		2.7–3.6	$V_{CC} - 0.2$			V	I _{OH} = -100 μA	
			3.0	2.0			V	I _{OH} = -12 mA	
V _{OL}	Output LOW Voltage		2.7			0.2	V	I _{OL} = 100 μA	
			3.0			0.8	V	I _{OL} = 12 mA	
I _{I(HOLD)}	Bushold Input Minimum Drive		3.0	75			μΑ	$V_{I} = 0.8V$	
(Note 4)				-75			μΑ	$V_{I} = 2.0V$	
I _{I(OD)}	Bushold Input Over-Drive		3.0	500			μΑ	(Note 5)	
(Note 4)	Current to Change State			-500			μΑ	(Note 6)	
l _l	Input Current		3.6			10	μA	$V_{I} = 5.5V$	
		Control Pins	3.6			±1	μΑ	$V_I = 0V \text{ or } V_{CC}$	
		Data Pins	3.6			-5	μΑ	$V_I = 0V$	
		Data Filis	5.0			1	μΑ	$V_I = V_{CC}$	
I _{OFF}	Power Off Leakage Curren	t	0			±100	μΑ	$0V \le V_1 \text{ or } V_0 \le 5.5V$	
I _{PU/PD}	Power up/down 3-STATE Output Current		0–1.5V			±100	μA	$V_0 = 0.5V$ to 3.0V $V_1 = GND$ or V_{CC}	
I _{OZL}	3-STATE Output Leakage	Current	3.6			-5	μA	$V_{O} = 0.5V$	
I _{OZH}	3-STATE Output Leakage	Current	3.6			5	μA	V _O = 3.0V	
I _{OZH} +	3-STATE Output Leakage	Current	3.6			10	μA	$V_{CC} < V_O \le 5.5V$	
I _{CCH}	Power Supply Current		3.6			0.19	mA	Outputs HIGH	
I _{CCL}	Power Supply Current		3.6			5	mA	Outputs LOW	
I _{CCZ}	Power Supply Current		3.6			0.19	mA	Outputs Disabled	

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DC Electrical Characteristics (Continued)

		v _{cc}	T _A =−40°C to +85°C					
Symbol	Parameter	•cc (V)	Min	Typ Units (Note 3)		Conditions		
I _{CCZ} +	Power Supply Current	3.6			0.19	mA	$V_{CC} \le V_O \le 5.5V$, Outputs Disabled	
ΔI_{CC}	Increase in Power Supply Current (Note 7)	3.6			0.2	mA	One Input at $V_{CC} - 0.6V$ Other Inputs at V_{CC} or GND	

Note 3: All typical values are at V_{CC} = 3.3V, T_A = 25°C.

Note 4: Applies to bushold versions only (74LVTH2244).

Note 5: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 6: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

Note 7: This is the increase in supply current for each, input that is at the specified voltage level rather than V_{CC} or GND.

Dynamic Switching Characteristics (Note 8)

Symbol	nbol Parameter		Parameter V _{CC}		$T_A = 25^{\circ}C$			Units	Conditions	
Gymbol	r arameter	(V)	Min	Тур Мах		Onits	$\textbf{C}_{\textbf{L}}=\textbf{50}~\textbf{pF},~\textbf{R}_{\textbf{L}}=\textbf{500}\Omega$			
V _{OLP}	Quiet Output Maximum Dynamic V _{OL}	3.3		0.8		V	(Note 9)			
VOLV	Quiet Output Minimum Dynamic VOL	3.3		-0.8		V				

Note 8: Characterized in SOIC package. Guaranteed parameter, but not tested.

Note 9: Max number of outputs defined as (n). n–1 data inputs are driven 0V to 3V. Output under test held LOW.

AC Electrical Characteristics

		$T_{A} = -40^{\circ}C \text{ to } +85^{\circ}C$ $C_{L} = 50 \text{ pF, } R_{L} = 500\Omega$					
Symbol	Parameter	v	$V_{\rm CC} = 3.3 V \pm 0.3$	3V	$V_{CC} = 2.7V$		Units
		Min	Тур	Max	Min	Max	
			(Note 10)				
t _{PLH}	Propagation Delay Data to Output	1.0		4.4	1.0	5.3	ns
t _{PHL}		1.0		4.1	1.0	4.4	115
t _{PZH}	Output Enable Time	1.0		5.9	1.0	7.7	ns
t _{PZL}		1.1		5.5	1.1	6.2	ns
t _{PHZ}	Output Disable Time	1.9		6.1	1.9	6.8	ns
t _{PLZ}		1.8		4.5	1.8	4.5	115
t _{OSHL}	Output to Output Skew			1.0		1.0	ns
t _{OSLH}	(Note 11)						

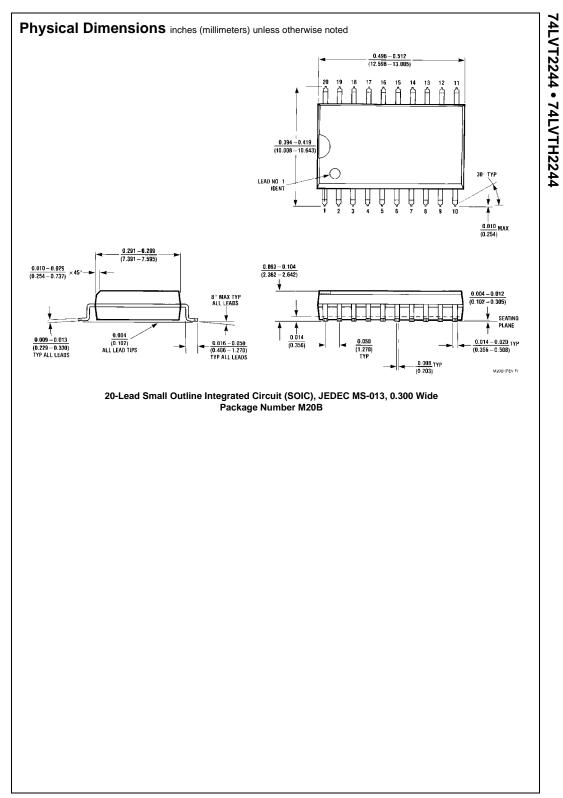
Note 10: All typical values are at V_{CC} = 3.3V, T_A = 25^{\circ}C.

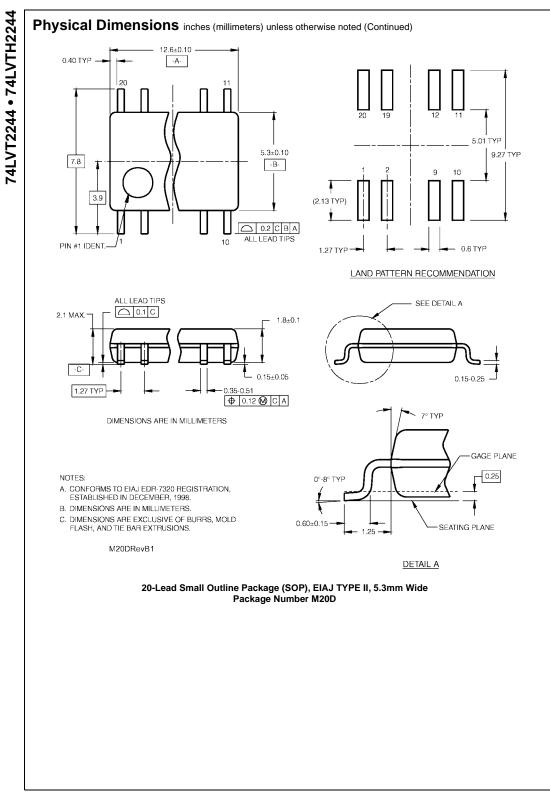
Note 11: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (to_{SHL}) or LOW-to-HIGH (to_{SLH}).

Capacitance (Note 12)

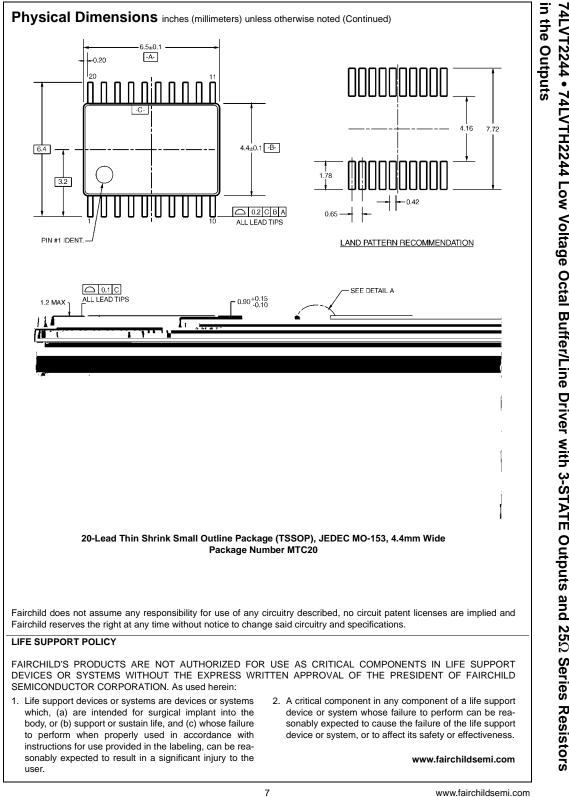
Symbol	Parameter	Conditions	Typical	Units
C _{IN}	Input Capacitance	$V_{CC} = 0V, V_I = 0V \text{ or } V_{CC}$	3	pF
C _{OUT}	Output Capacitance	$V_{CC} = 3.0V$, $V_{O} = 0V$ or V_{CC}	6	pF

Note 12: Capacitance is measured at frequency f = 1 MHz, per MIL-STD-883B, Method 3012.	





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